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Integration of organic electrochemical transistors and immuno-affinity membranes for label-free detection of interleukin-6 in the physiological concentration range through

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Electronic Supplementary Information

Integration of Organic Electrochemical Transistors and Immuno-Affinity Membranes for Label-Free Detection of Interleukin-6 at the Physiological Concentration Range through Antibody-Antigen Recognition

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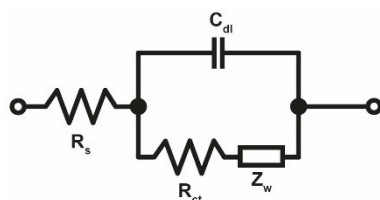


Figure S1. Randles equivalent circuit: dynamic solution resistance (R_s), double layer capacitance measured between the gold electrode and the electrolyte solution (C_{dl}), charge transfer resistance (R_{ct}) and Warburg Element (Z_w).

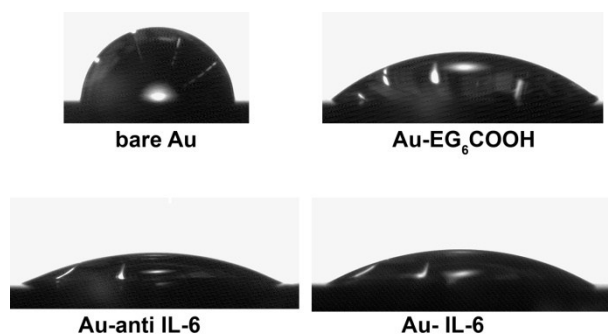


Figure S2. Static water contact angle measurements of gold-coated substrates after each functionalization and incubation steps.

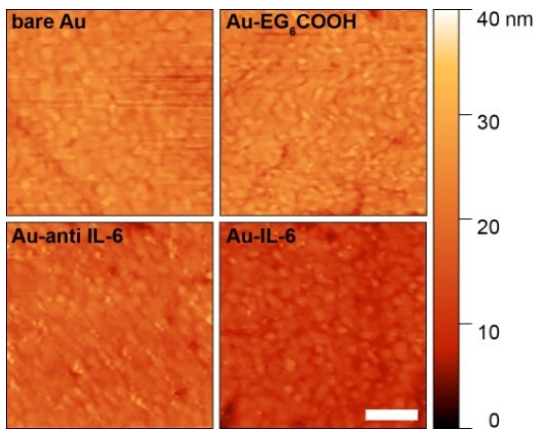


Figure S3. AFM images (scale bar: 200 nm) of a gold-coated surface after each functionalization and incubation step.

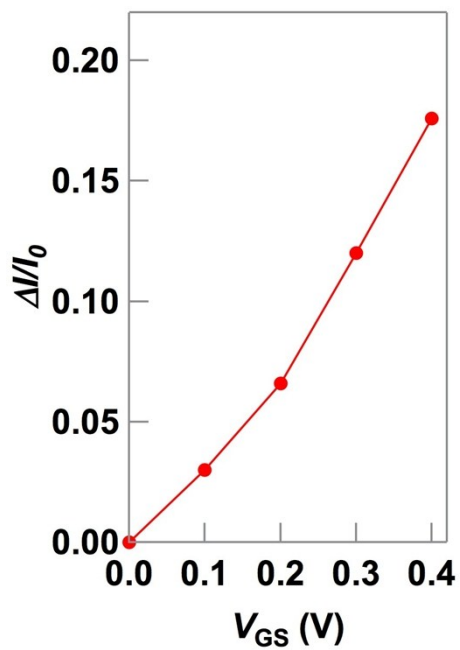


Figure S4. $\Delta I/I_0$ parameter as a function of V_{GS} (V_{DS} at -0.1 V) of OECT working with bare Au gate electrode